

2N7637-GA Information



For Reference Only

Part Number 2N7637-GA

Manufacturer GeneSiC Semiconductor

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description TRANS SJT 650V 7A TO-257

Package TO-257-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2N7637-GA Specifications

Manufacturer Part Number	2N7637-GA
Manufacturer	GeneSiC Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-257-3
Series	-
FET Type	-
Technology	SiC (Silicon Carbide Junction Transistor)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	7A (Tc) (165°C)
Drive Voltage (Max Rds On, Min Rds On)	-
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	720pF @ 35V
Vgs (Max)	-
FET Feature	-
Power Dissipation (Max)	80W (Tc)
Rds On (Max) @ Id, Vgs	170 mOhm @ 7A
Operating Temperature	-55°C ~ 225°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-257
Package / Case	TO-257-3
	Report errors?

2N7637-GA Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2N7637-GA Payment Methods



















2N7637-GA Shipping Methods













If you have any question about 2N7637-GA, please do not hesitate to contact us!

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